Vishay Semiconductors

Medium Power Silicon Rectifier Diodes, 12 A



PRODUCT SUMMARY				
I _{F(AV)}	12 A			
Package	DO-203AA (DO-4)			
Circuit configuration	Single diode			

FEATURES

- Voltage ratings from 50 V to 1000 V
- High surge capability
- Low thermal impedance
- High temperature rating
- Can be supplied as JAN and JAN-TX devices in accordance with MIL-S-19500/260
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

MAJOR RATINGS AND CHARACTERISTICS					
TEST CONDITIONS	VALUES	UNITS			
	12	A			
T _C	150	O°			
50 Hz	230	٨			
60 Hz	240	A			
50 Hz	260	– A ² s			
60 Hz	240	A-S			
	- 65 to 200	C°			
Range	50 to 1000	V			
	TEST CONDITIONS T _C 50 Hz 60 Hz 50 Hz 60 Hz 60 Hz 60 Hz	TEST CONDITIONS VALUES Image: T_C 12 T_C 150 50 Hz 230 60 Hz 240 50 Hz 260 60 Hz 240 - 65 to 200 - 65 to 200			

Note

JEDEC registered values are in bold

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _C = - 65 °C TO 200 °C) V	V _{R(RMS)} , MAXIMUM RMS REVERSE VOLTAGE (T _C = - 65 °C TO 200 °C) V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE (T _C = - 65 °C TO 200 °C) V	V _{RM} , MAXIMUM DIRECT REVERSE VOLTAGE (T _C = - 65 °C TO 200 °C) V
1N1199A	50	35	100	50
1N1200A	100	70	200	100
1N1201A	150	105	300	150
1N1202A	200	140	350	200
1N1203A	300	210	450	300
1N1204A	400	280	600	400
1N1205A	500	350	700	500
1N1206A	600	420	800	600
1N3670A	700	490	900	700
1N3671A	800	560	1000	800
1N3672A	900	630	1100	900
1N3673A	1000	700	1200	1000

Notes

JEDEC registered values are in bold

• Basic part number indicates cathode to case; for anode to case, add "R" to part number, e.g., 1N1199RA

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1N1...A, 1N36..A Series

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FORWARD COM	NDUCTION					
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current			180° sinusoidal conduction		12	А
at case temperature		I _{F(AV)}	180 Sinusoidal conduction		150	°C
	Maximum peak one cycle non-repetitive surge current		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V _{RRM} applied	230	A
Maximum peak one cy			Half cycle 60 Hz sine wave or 5 ms rectangular pulse		240	
surge current			Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load	275	
			Half cycle 60 Hz sine wave or 5 ms rectangular pulse	condition and with V _{RRM} applied following surge = 0 V	285	
Mar. 1	_		t = 10 ms	With rated V _{RRM} applied	260	
Maximum I ² t for fusin	Maximum I ² t for fusing		t = 8.3 ms	following surge, initial T _J = 200 °C	240	A ² s
Maximum I ² t for indiv	Maximum I ² t for individual device fusing		t = 10 ms	With $V_{RRM} = 0 V$ following surge, initial $T_J = 200 ^\circ\text{C}$	370	
device fusing			t = 8.3 ms		340	
Maximum l²√t for indi device fusing	Maximum I ² √t for individual device fusing		t = 0.1 ms to 10 ms, V_{RRM} = 0 V following surge		3715	A²√s
Maximum forward vol	Maximum forward voltage drop		I _{F(AV)} = 12 A (38 A peak), T _C = 25 °C		1.35	V
	$V_{\text{RRM}} = 50 \text{ V}$				3.0	-
	$V_{RRM} = 100 V$				2.5	
	V _{RRM} = 150 V					
	V _{RRM} = 200 V				2.0	
	V _{RRM} = 300 V		Maximum rated $I_{F(AV)}$ and $T_{\rm C}$		1.75	mA
Maximum average reverse current	V _{RRM} = 400 V	– I _{R(AV)} ⁽²⁾			1.5	
	V _{RRM} = 500 V				1.25	
	V _{RRM} = 600 V				1.0	
	$V_{RRM} = 700 V$				0.9	-
	V _{RRM} = 800 V				0.8	
	V _{RRM} = 900 V				0.7	
	V _{RRM} = 1000 V				0.6	

Notes

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⁽¹⁾ I²t for time $t_x = I^2 \sqrt{t} x \sqrt{t_x}$

⁽²⁾ Maximum peak reverse current (I_{RM}) under same conditions $\approx 2 \text{ x rated } I_{R(AV)}$



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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum operating ca storage temperature ra		T _C , T _{Stg}		- 65 to 200	°C
Maximum internal thermal resistance, junction to case		R _{thJC}	DC operation	2.0	°C/W
Thermal resistance, case to sink		R _{thCS}	Mounting surface, smooth, flat and greased		
Mounting torque	minimum		To a construction of the construction of the construction	1.36 (12)	N ⋅ m (lbf ⋅ in)
	maximum		Torque applied to nut; non-lubricated threads	1.69 (15)	
	minimum			1.07 (9.45)	
	maximum		Torque applied to nut; lubricated threads	1.30 (11.55)	
	minimum		The second state of the second state of the second	1.17 (10.35)	
	maximum		Torque applied to device case; lubricated threads	1.43 (12.65)	
Approvimate weight				7.0	g
Approximate weight				0.25	oz.
Case style			JEDEC DO-203AA (DO		A (DO-4)

Note

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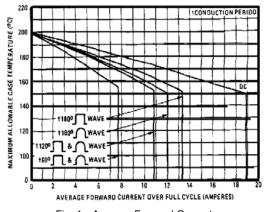


Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature

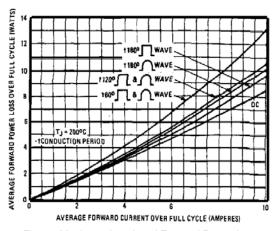
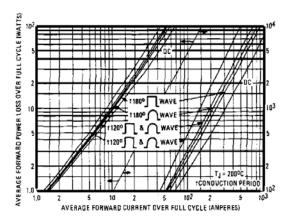
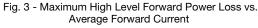


Fig. 2 - Maximum Low Level Forward Power Loss vs. Average Forward Current





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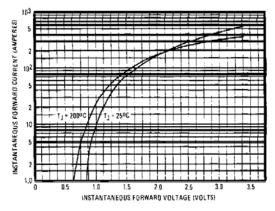


Fig. 4 - Maximum Forward Voltage vs. Forward Current

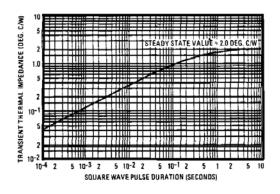


Fig. 5 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration

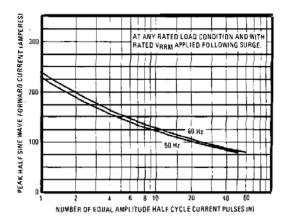


Fig. 6 - Maximum Non-Repetitive 50 Hz Surge Current vs. Number of Current Pulses

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95311		
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R 0.40 R (0.02)

Ø 6.8 (0.27)

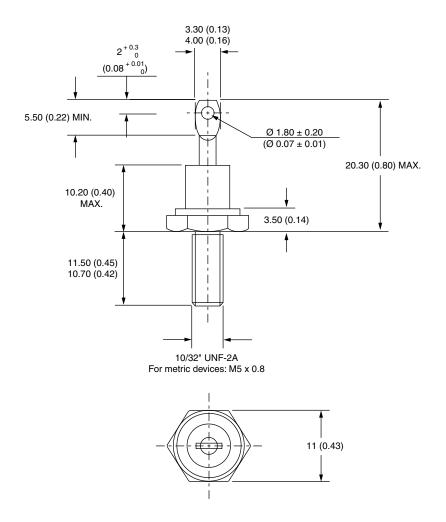
 0.8 ± 0.1

 (0.03 ± 0.004)



DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)







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